



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

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## Peak Emission Wavelength: 850nm

The 850nm Point Source Series is designed for applications requiring high accuracy and precision as well as uniform spectral emission. Custom package solutions and sorting are available.

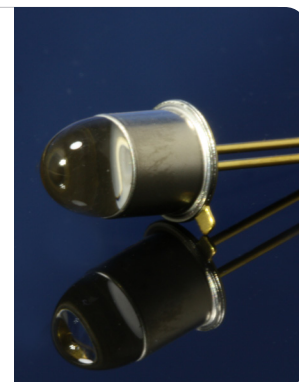
### FEATURES

- > Hermetically Sealed TO-18
- > Emitting Window Diameter  $\Phi$  150 $\mu$ m
- > Gold Plated Dome Lens
- > High Reliability / High Output Power

> Extremely Narrow Radiation Pattern

### APPLICATIONS

- > Optical Scanning / Optical Sensors
- > Linear & Rotary Encoder
- > Edge Sensing



## Absolute Maximum Ratings (Ta=25°C)



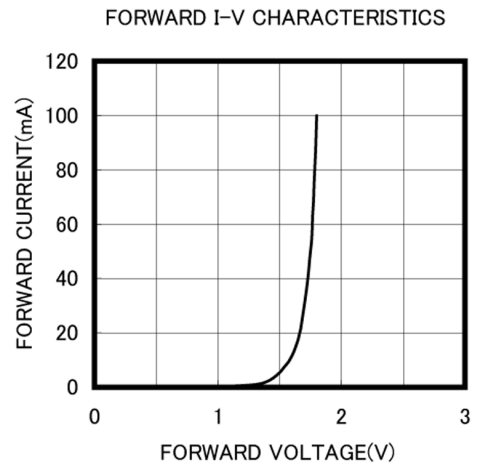
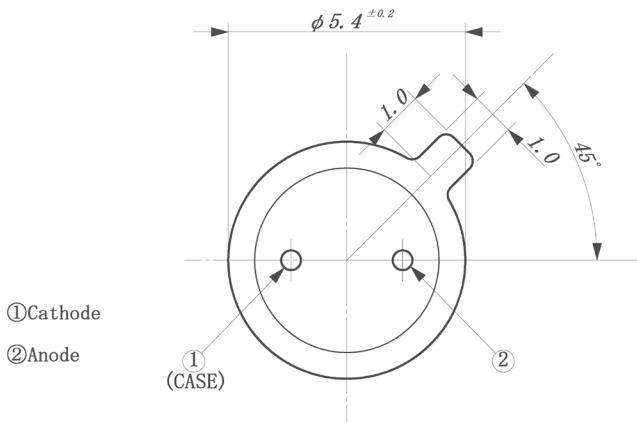
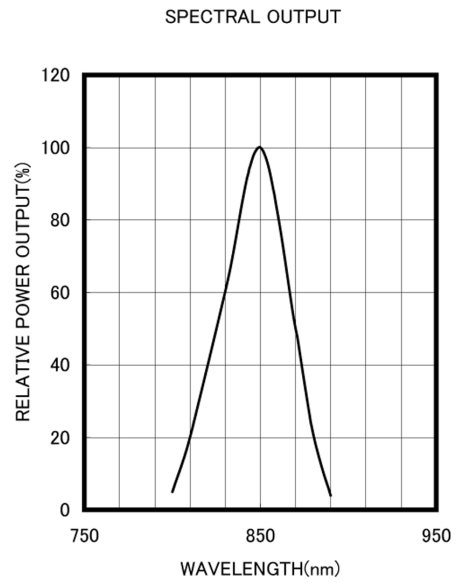
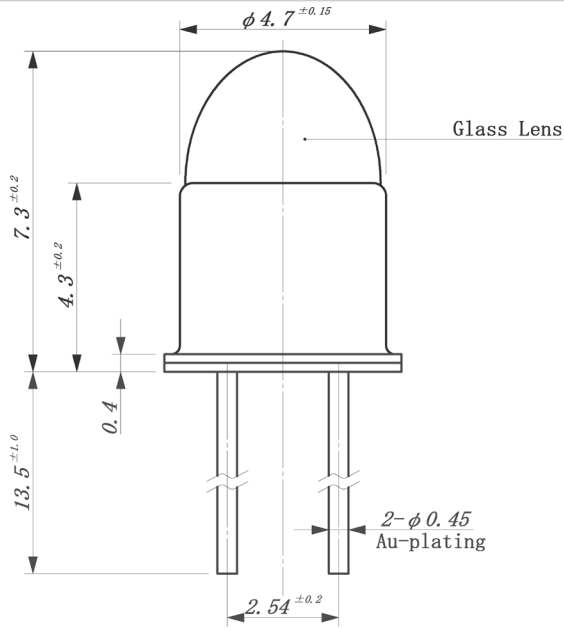
ITEMS	SYMBOL	RATINGS	UNIT
Forward Current (DC)	IF	100	mA
Forward Current (Pulse)*1	IFP	0.8	A
Reverse Voltage	VR	5	V
Power Dissipation	PD	180	mW
Operating Temperature Range	Topr	-30 ~ +100	°C
Storage Temperature Range	Tstg	-40 ~ +125	°C
Junction Temperature	Tj	125	°C
Lead Soldering Temperature*2	Tls	260	°C

\*1: Tw=10 $\mu$ sec, T=10msec; \*2: Time 5 Sec max, Position: Up to 3mm from the body.

## Electrical & Optical Characteristics (Ta = 25°C)

ITEMS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Power Output	PO	IF=50mA	2.0	3.3	--	mW
Forward Voltage	VF	IF=50mA	--	1.7	2.2	V
Reverse Current	IR	VR=5V	--	--	100	$\mu$ A
Peak Emission Wavelength	$\lambda_p$	IF=50mA	--	850	--	nm
Spectral Line Half Width	$\Delta\lambda$	IF=50mA	--	45	--	nm
Half Intensity Beam Angle	$\Theta$	IF=50mA	--	$\pm 2.5$	--	deg
Cut-Off Frequency	fc	*3	--	20	--	MHz
Temperature Coefficient of PO	P/T	IF=10mA	--	-0.05	--	%/°C
Temperature Coefficient of VF	V/T	IF=10mA	--	-2	--	mV/°C
Switching Time	tr, tf	IF=50mA	--	30	--	ns

\*3: IFP=50mA+20mA<sub>p-p</sub>.



Unit: mm, Tolerance:  $\pm 0.2$

